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# Magnetic domain texture and the Dzyaloshinskii-Moriya interaction in Pt/Co/IrMn and Pt/Co/FeMn thin films with perpendicular exchange bias

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Antiferromagnetic materials present us with rich and exciting physics, which we can exploit to open new avenues in spintronic device applications. We explore perpendicularly magnetized exchange biased systems of Pt/Co/IrMn and Pt/Co/FeMn, where the crossover from paramagnetic to antiferromagnetic behavior in the IrMn and FeMn layers is accessed by varying the thickness. We demonstrate, through magneto-optical imaging, that the magnetic domain morphology of the ferromagnetic Co layer is influenced by the Néel order of the antiferromagnet (AFM) layers. We relate these variations to the anisotropy energy of the AFM layer and the ferromagnet-antiferromagnet (FM-AFM) inter-layer exchange coupling. We also quantify the interfacial Dzyaloshinskii-Moriya interaction (DMI) in these systems by Brillouin light scattering spectroscopy. The DMI remains unchanged, within experimental uncertainty, for different phases of the AFM layers, which allows us to conclude that the DMI is largely insensitive to both AFM layer spin order and exchange bias. Understanding such fundamental mechanisms is crucial for the development of future devices employing chiral spin textures, such as Néel domain walls and skyrmions, in FM-AFM heterostructures.

## I. INTRODUCTION

The field of spintronics [1] aims to realize low-power and high-performance next-generation memory [2] and logic devices [3, 4] through the manipulation of the electron spin. Influencing ferromagnet (FM) spins using an antiferromagnet (AFM) is an emerging branch of spintronics [5–9]. The magnetization in a FM layer can be controlled by an adjacent AFM layer through the interfacial coupling between the two layers [10]. AFMs have several other advantages as well. For instance, the net magnetization is zero due to the compensation of magnetic moments at the atomic level. The elimination of stray fields could prove to be vital in integrated devices with low dimensions because such parasitic fields (e.g., from a FM) present complications, such as crosstalk between neighboring devices, susceptibility to external magnetic fields, etc. Furthermore, AFMs possess excellent magneto-transport properties which would allow the generation of large spin currents through which magnetization in an adjacent FM layer could be efficiently switched [6, 9, 11]. AFMs also offer dynamics in the terahertz range suitable for ultrafast information processing [12].

The exchange interaction is at the heart of magnetic behavior in materials. It comprises a symmetric and an antisymmetric term. The symmetric term, the Heisenberg interaction, prefers collinear orientation of adjacent spins. The antisymmetric term, the Dzyaloshinskii-Moriya interaction (DMI) [13, 14], prefers canted orientation of neighboring spins. In order to exist, the

DMI needs spin-orbit interaction in an asymmetric crystal field, such as in heterostructures lacking spatial inversion symmetry. The DMI gives rise to chiral spin textures [15, 16], which results in many different interesting phenomena [17, 18]. In ultrathin film multilayers, the DMI is of the interfacial form and has been reported to be present at the heavy-metal/ferromagnet (HM/FM) interface [17, 19], at the FM/oxide interface [20, 21], and more recently, at the FM/AFM interface [22]. The DMI stabilizes spin structures such as chiral Néel domain walls (DWs) [23] and skyrmions [24], both of which can be driven as information carriers [2, 25] by electric currents via the spin Hall torque generated in an adjacent HM [26] and/or AFM [9] layer.

In this work, we investigate ultrathin film systems of Pt/Co/IrMn and Pt/Co/FeMn, which exhibit perpendicular magnetic anisotropy (PMA) and perpendicular exchange bias (PEB) [27–30]. These multilayers are potentially of interest because of the coincidence of the DMI with a vertical exchange field that could substitute the need for an externally applied field to stabilize skyrmion bubbles [31]. We explore the interaction mechanisms at the interfaces, in particular the changes in the magnetic domain texture and the DMI, when going through the paramagnet to AFM phase transition of the AFM layers by systematically varying the thickness of the layers. When the AFM layer is in the paramagnetic phase, the domains of the FM layer are large and contain networks of unreversed narrow domains. As antiferromagnetic order sets in, bubble domains with smooth DWs are nucleated. The DWs eventually become rough at the onset of the exchange bias field. The nucleation density also increases significantly. We relate this variation in the domain morphology to the interplay between the anisotropy energy of the AFM layer and the exchange energy at the interface between the FM and the AFM layers. We iden-

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tify the Néel and the blocking temperature of IrMn to confirm paramagnetic behavior at low layer thicknesses. We do this by exploiting the previously shown fact [32] that these temperatures can be tuned by varying the AFM layer thickness. Finally, we evaluate the interfacial DMI in these systems by Brillouin light scattering (BLS) [33–35]. We measure the DMI at four different phases of the AFM layer: paramagnet phase, AFM phase without exchange bias (EB), AFM phase at the onset of EB, and AFM phase with a large EB. The DMI is similar for all four phases, from which we conclude that there is little influence of AFM spin order or EB on the DMI in these systems. Investigating such interactions provide insight towards the development of future DW and skyrmion devices incorporating an FM-AFM bilayer.

## II. MULTILAYER SYSTEMS

The material systems that we studied consist of Pt(2 nm)/Co(1 nm)/Ir<sub>20</sub>Mn<sub>80</sub>( $t_{\text{IrMn}}$ ) and Pt(2 nm)/Co(0.6 nm)/Fe<sub>50</sub>Mn<sub>50</sub>( $t_{\text{FeMn}}$ ) trilayers deposited on a 5 nm Ta seed layer on a thermally oxidized Si substrate. The Ta seed layer provides a (111) texture for the Pt and Co layers, and consequently, for the IrMn and FeMn layers. Such a crystal orientation is required for IrMn [36] and FeMn [37] for an effective exchange coupling leading to a large EB. The layers were grown by dc magnetron sputtering at a base pressure of  $3 \times 10^{-6}$  Pa ( $2 \times 10^{-8}$  Torr) and at an Ar working pressure of 0.33 Pa (2.5 mTorr). A 3 nm capping layer of Pt or Ta was also deposited on top of the stacks in order to prevent oxidation. A change in capping layer has no effect on the magnetic properties we measure here.

The systems exhibit a uniaxial magnetic anisotropy perpendicular to the plane of the sample. To ensure this, an optimum thickness of Co layer was chosen by systematically varying the thickness for each system. The AFM layer thicknesses were kept constant at 5 nm for IrMn and at 4 nm for FeMn at which the respective systems exhibit an EB field at room temperature. Fig. 1(a) shows coercive fields ( $H_c$ ), obtained from polar MOKE hysteresis loops, as a function of Co layer thickness.  $H_c$  is half the difference between the two switching fields. PMA could be achieved for a range of Co thicknesses: 0.8-1.4 nm for the IrMn system, and 0.4-1 nm for the FeMn system. Outside this range the sample magnetization lies in-plane. We chose the working Co thickness to be  $t_{\text{Co}} = 1$  nm for the IrMn system because at this thickness the system exhibits a large coercivity and thus provides a stable perpendicular magnetization. For the same reason, we chose  $t_{\text{Co}} = 0.6$  nm for the FeMn system. Hysteresis loops at these particular Co thicknesses are shown in Fig. 1(b). The magnetization in the Co layer sets the pinning direction of the IrMn or FeMn layer resulting in the PEB. The EB field ( $H_{\text{ex}}$ ) decreases while the Co layer thickness increases (Fig. 1(c)) for both systems, in the range where the perpendicular anisotropy

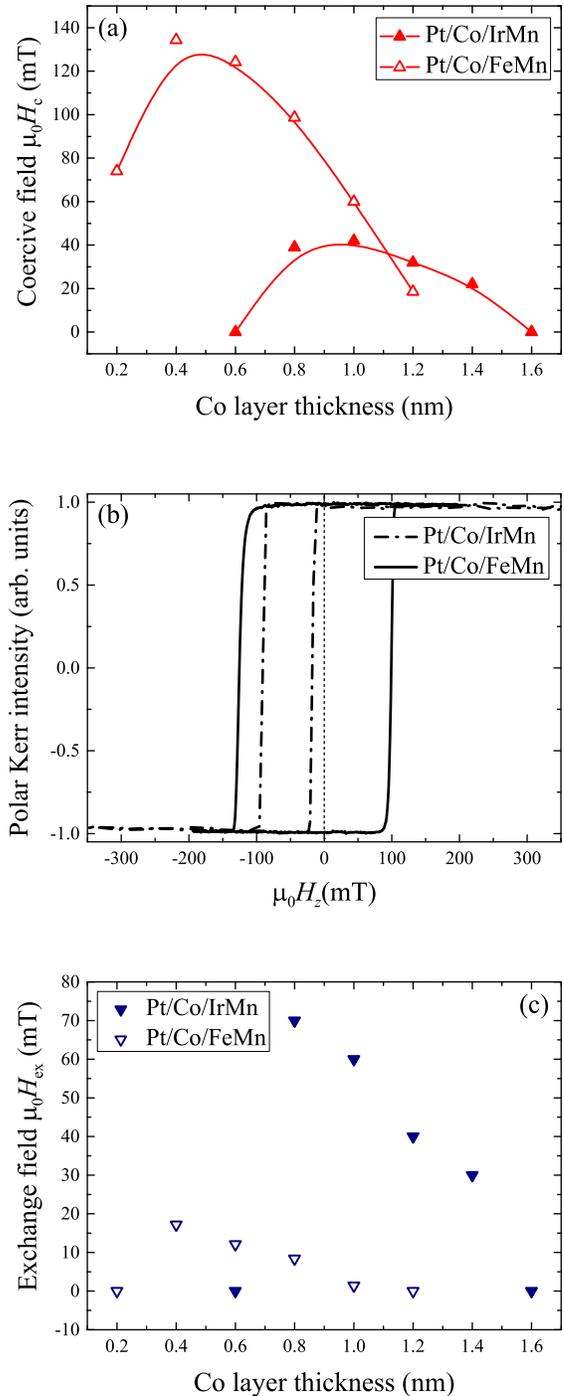


FIG. 1. Coercivity and exchange bias for the systems of Pt(2 nm)/Co( $t_{\text{Co}}$ )/IrMn(5 nm) and Pt(2 nm)/Co( $t_{\text{Co}}$ )/FeMn(4 nm): (a) Coercivity  $\mu_0 H_c$  as a function of Co layer thickness  $t_{\text{Co}}$  from which the optimum thickness is chosen to be 1 nm for the IrMn, and 0.6 nm for the FeMn system. The solid lines are guides to the eye. (b) Polar MOKE hysteresis loops of Pt(2 nm)/Co(1 nm)/IrMn(5 nm) and Pt(2 nm)/Co(0.6 nm)/FeMn(4 nm) measured at room temperature. (c) Exchange bias field  $\mu_0 H_{\text{ex}}$  as a function of Co layer thickness.

is dominant.  $H_{\text{ex}}$  is half of the sum between the two switching fields. The PEB is present in the samples in the as-grown state and does not require any post-growth processing.

### III. EXCHANGE BIAS AND DOMAIN MORPHOLOGY IN PT/CO/IRMN

#### A. Magnetic properties

To investigate how the exchange coupling at the FM-AFM interface modifies the domain texture we vary the AFM layer thickness, which dictates the spin order. We first concentrate on the IrMn system of Pt(2 nm)/Co(1 nm)/Ir<sub>20</sub>Mn<sub>80</sub>( $t_{\text{IrMn}}$ ), where the IrMn layer was varied from 1 to 10 nm. A summary of coercive fields ( $H_c$ ) and exchange bias fields ( $H_{\text{ex}}$ ) measured at room temperature is shown in Fig. 2. These magnetic properties were extracted from hysteresis loops measured by polar magneto-optic Kerr effect (MOKE) magnetometry.

The onset of EB occurs at  $\approx 2.3$  nm of IrMn.  $H_{\text{ex}}$  rises steadily and stabilizes at  $\mu_0 H_{\text{ex}} = 50$  mT from 3.5 nm onward. The coercive field peaks at the same 2.3 nm of IrMn at which the exchange field starts to develop. After peaking it gradually drops and settles to a saturation value of  $\mu_0 H_c = 40$  mT at the same thickness of 3.5 nm at which the exchange field stabilizes. The trends closely match with those that were reported for similar systems with in-plane magnetization [38]. The initial increase in coercivity occurs at the onset of the AFM phase of IrMn and start of coupling with the Co layer [32, 38]. At 1 nm layer thickness the IrMn is a paramagnet. As the thickness is increased, the AFM phase sets in and there is an exchange interaction at the Co/IrMn interface. The beginning of this phase transition is marked by the increase in coercivity at  $\approx 1.7$  nm of IrMn. As the Co layer is rotated, it also drags the spins of the IrMn layer along with it, causing an enhancement in coercivity. The Co spins are able to drag the IrMn spins because the volume anisotropy energy ( $K_{\text{AFM}}$ ) of the AFM layer is smaller than the exchange energy ( $J_{\text{FM-AFM}}$ ) at the interface between the FM and the AFM layers ( $K_{\text{AFM}} < J_{\text{FM-AFM}}$ ). As the IrMn thickness is increased further,  $K_{\text{AFM}}$  becomes larger, resulting in further enhancement in coercivity until a critical thickness of  $\approx 2.3$  nm is reached when it is no longer energetically favorable for the Co layer to drag the coupled IrMn spins. In other words, from this critical thickness onward,  $K_{\text{AFM}}$  is large enough to resist the torque from the FM Co layer ( $K_{\text{AFM}} > J_{\text{FM-AFM}}$ ). Thus, the coercivity gradually decreases while the exchange field starts to increase.

#### B. Domain morphology

The anisotropy energy of the AFM, and consequently the FM-AFM inter-layer coupling has a profound effect

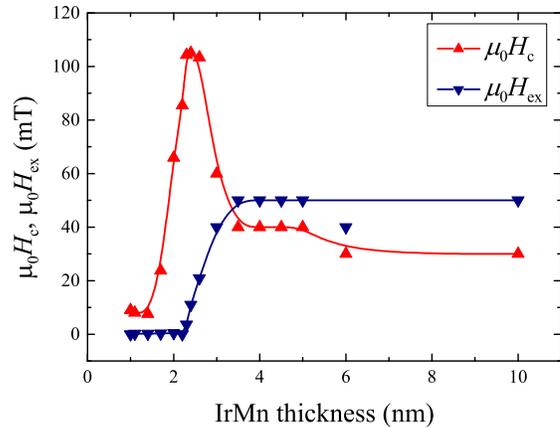


FIG. 2. IrMn layer thickness dependence of the exchange bias field  $\mu_0 H_{\text{ex}}$  (blue down triangles) and coercive field  $\mu_0 H_c$  (red up triangles) for Pt(2 nm)/Co(1 nm)/IrMn( $t_{\text{IrMn}}$ ). The solid lines are guides to the eye. Onset of exchange bias occurs at  $\approx 2.3$  nm of IrMn, at which point the coercivity peaks.

on the domain morphology. Fig. 3 shows the variation in domain structure as a function of IrMn layer thickness. The domains were imaged using a wide-field Kerr microscope in the polar configuration, at which it is sensitive to out-of-plane (OOP) magnetization [39]. Images captured before and after the application of an OOP field were subtracted, resulting in these difference images. At low IrMn thicknesses, when it is in the paramagnet phase, the domains are large and threaded with disconnected networks of unreversed narrow domains (Fig. 3(a-b)). These narrow domains form as a DW gets pinned at a defect and bends around it. These domains continue to exist since they are bounded by homochiral DWs, which require large fields to annihilate because they have the same chirality due to the DMI, and thus present a topological energy barrier [40]. At  $\approx 1.7$  nm of IrMn, coupling is initiated due to AFM ordering and the domain morphology changes significantly. Now bubble domains form with relatively smooth DWs instead of the networks of narrow domains as the DWs are no longer pinned at defect sites; Fig. 3(c). This is due to the application of relatively larger fields to nucleate domains and propagate DWs, because of the increase in coercivity of the film brought about by the FM-AFM coupling. It is also because of this enhancement in coercivity that the nucleation density increases significantly with IrMn thickness as even larger fields are now necessary to nucleate domains. This is depicted in Fig. 3(d-e). At the critical thickness of  $\approx 2.3$  nm, the EB field starts to set in and the DWs start to become rough (Fig. 3(e-f)) due to enhanced pinning brought about by the EB, which complicates the spin structure and increases disorder. Eventually, the DWs become even rougher when the system exhibits a stable EB field from 3.5 nm onward as the anisotropy energy of the AFM layer becomes robust; Fig. 3(g-h).

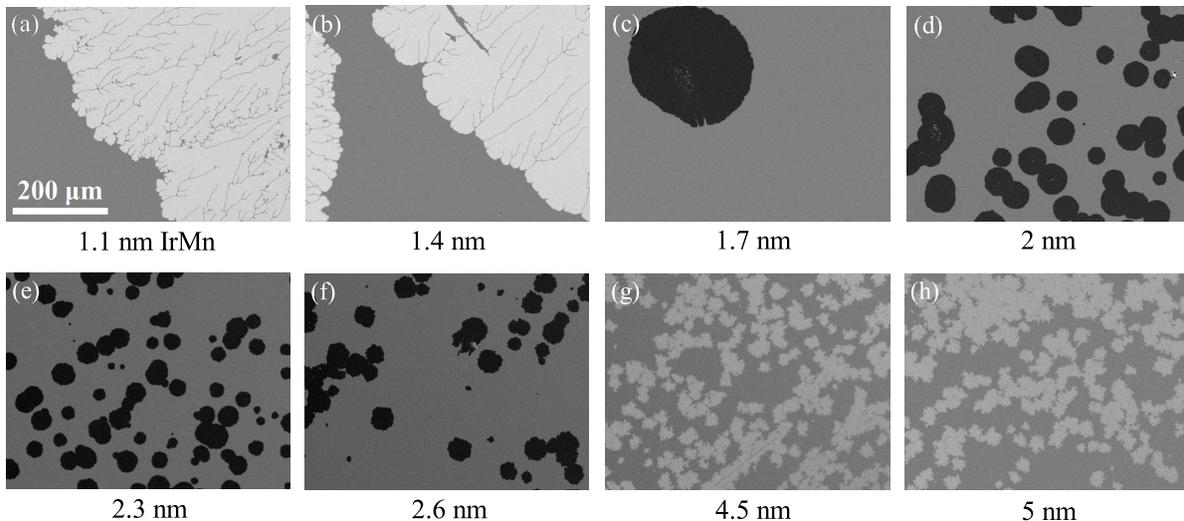


FIG. 3. Kerr microscope difference images showing the propagation of magnetic domains after  $\mu_0 H_z$  field pulses, which were applied for a few seconds, and ranged from 5 to 100 mT depending on the coercivity of the sample. The bright/dark regions (relative to grey) represent the areas swept out by DWs during the field pulse. The domain texture changes significantly as a function of IrMn layer thickness. At low IrMn thicknesses (paramagnet phase), the domains are large (a-b). At 1.7 nm thickness, the AFM phase sets in and bubble domains are nucleated from isolated pinning sites (c). An increase in nucleation density occurs (d) at a slightly thicker IrMn layer. Further increasing the thickness the DWs become rough (e-f) due to the onset of EB. Eventually, the DWs become rougher when the EB stabilizes (g-h).

### C. Investigation of paramagnetic behavior

We confirm paramagnetic behavior at low thicknesses by investigating the Néel temperature ( $T_N$ ) and blocking temperature ( $T_B$ ) of the IrMn layer. We do the magnetic characterization in a 2-300 K vibrating sample magnetometer (VSM). For this, we initially cooled the sample from room temperature to 5 K while applying a static perpendicular field of 200 mT, which is large enough to completely saturate the Co layer. Then temperature dependence measurements were done as a series of hysteresis loops at increasing temperatures. Four repeats of field sweep were performed at each temperature to take into account the training effect [38] and the last loop was used for characterization. Fig. 4 shows the temperature dependence of  $H_c$  (red up triangles) and  $H_{ex}$  (blue down triangles) for three of the smaller thicknesses of IrMn (2, 1.4 and 1.1 nm). The thickness of the other layers are as previously.  $H_{ex}$  of all the samples falls with temperature and goes to zero at  $T_B$ . This is the temperature below which the AFM domains are stable and non-reversible.  $H_c$  also shows a downward trend with temperature until  $T_N$ , at which temperature there is no AFM ordering and the value of  $H_c$  is intrinsic to that of the Co layer [32]. At 2 nm IrMn  $T_B = 200$  K, while  $T_N$  lies just above room temperature (Fig. 2(a)). With decreasing IrMn thickness, both  $T_B$  and  $T_N$  shift down the temperature scale, as depicted in Fig. 2(b) and Fig. 2(c) for 1.4 and

1.1 nm of IrMn, respectively. This demonstrates that at low thicknesses, the IrMn layer is, indeed, in the paramagnetic phase and can be made to transit to the AFM phase just by cooling. These experiments also show that  $T_B$  and  $T_N$  can be tuned easily in this system by controlling the anisotropy energy of the IrMn layer via its thickness.

## IV. EXCHANGE BIAS AND DOMAIN MORPHOLOGY IN PT/CO/FEMN

The interaction mechanism, and subsequently the change in the domain structure is similar in the system of Pt(2 nm)/Co(0.6 nm)/Fe<sub>50</sub>Mn<sub>50</sub>( $t_{\text{FeMn}}$ ). Fig. 5 summarizes the dependence of  $H_c$ ,  $H_{ex}$ , and domain morphology on the FeMn layer thickness. The onset of EB occurs at  $\approx 4$  nm of FeMn (Fig. 5(a)) with a peak in coercivity. At  $\approx 1.5$  nm of thickness, the FeMn layer is in the paramagnet phase and the sample exhibit large domains containing network-like features, similar to the IrMn system; Fig. 5(b). At  $\approx 2.5$  nm of FeMn the AFM order sets in, causing an enhancement in coercivity due to FM-AFM inter-layer coupling. We now see the formation of bubble domains with smooth DWs (Fig. 5(c)) and without the network-like features. An increase of the FeMn layer causes the coercivity to increase further resulting in a substantial increases in nucleation density;

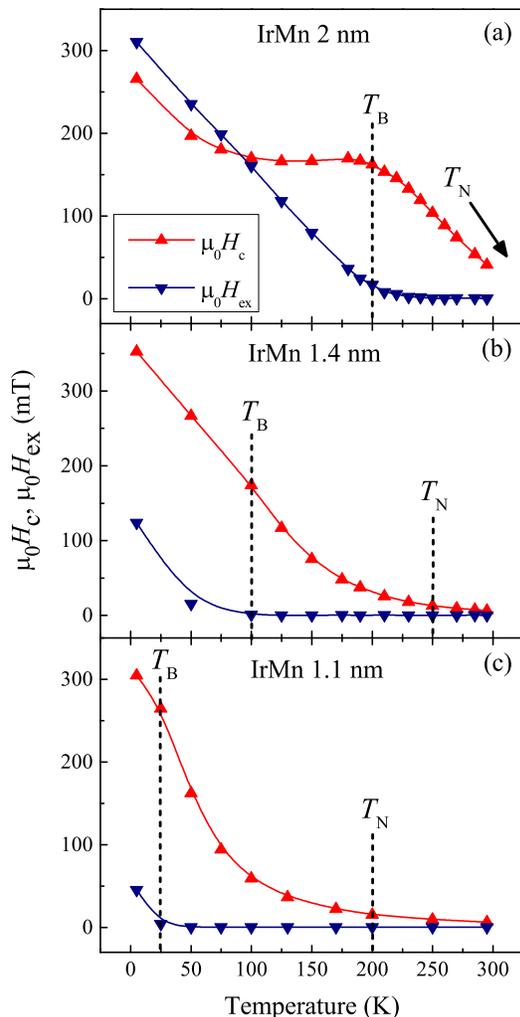


FIG. 4. Temperature dependence of the coercivity  $\mu_0 H_c$  (red up triangles) and exchange bias field  $\mu_0 H_{ex}$  (blue down triangles) for selected IrMn thicknesses. The solid lines are guides to the eye. Samples were initially cooled to 5 K in a 200 mT field. The blocking ( $T_B$ ) and Néel temperatures ( $T_N$ ) of the three samples are indicated by vertical dashed lines. At 2 nm IrMn (a)  $T_B = 200$  K, while  $T_N$  lies just above room temperature.  $T_B$  and  $T_N$  move to lower temperatures as the IrMn thickness is decreased to 1.4 nm (b) and then to 1.1 nm (c).

Fig. 5(d-e).

## V. DZHALOSHINSKII-MORIYA INTERACTION

We turn our attention to quantifying the DMI in these systems, and infer the DW spin texture. The DMI originates at the interface where adjacent spins of the FM undergo a chiral twist due to the exchange interaction mediated by an atom, with a large spin-orbit coupling, from the adjacent HM [17, 19] or AFM [22] layer. The

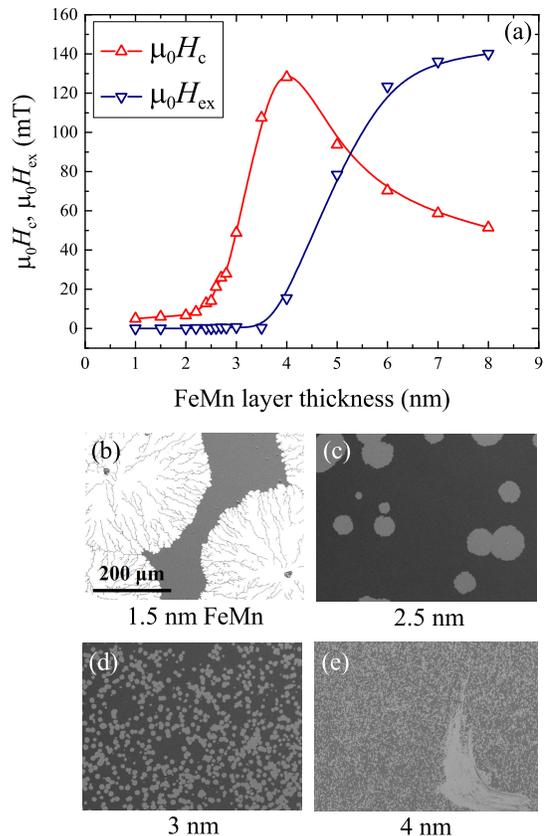


FIG. 5. (a) FeMn layer thickness dependence of the exchange field  $H_{ex}$  (blue down triangles) and coercive field  $H_c$  (red up triangles). The solid lines are guides to the eye. (b-e) Kerr microscope difference images showing the changes in domain structure as a function of FeMn layer thickness.

DMI acts locally on a DW manifesting as an effective in-plane field. This DMI field stabilizes the DW in a chiral Néel configuration [23, 41] by converting it from the magnetostatically favored Bloch configuration. We measured the DMI using Brillouin light scattering (BLS) spectroscopy [33–35]. In this method, we utilize the non-reciprocity of the DMI-induced frequency-shift and measure the Damon-Eshbach spin-wave frequencies for both field polarities. The frequency shift is then given by

$$\Delta f = \left| \frac{g\mu_B}{h} \right| \frac{2D_{\text{eff}}}{M_s} k = \left| \frac{g\mu_B}{h} \right| \frac{2D_s}{M_s t_{\text{FM}}} k,$$

where  $D_{\text{eff}}$  is the volumetric DMI constant that determines the sign and magnitude of the DMI vector,  $g$  is the spectroscopic  $g$ -factor taken to be 2.14 [42],  $M_s$  is the saturation magnetization,  $\mathbf{k}$  (with magnitude  $k$ ) is the wavevector of the spin waves,  $\mu_B$  is the Bohr magneton, and  $h$  is Planck constant. The sign of the frequency-shift depends on the direction of the magnetization and the propagation direction of the spin-waves. In the last equality,  $D_s$  is the interfacial DMI parameter, which rep-

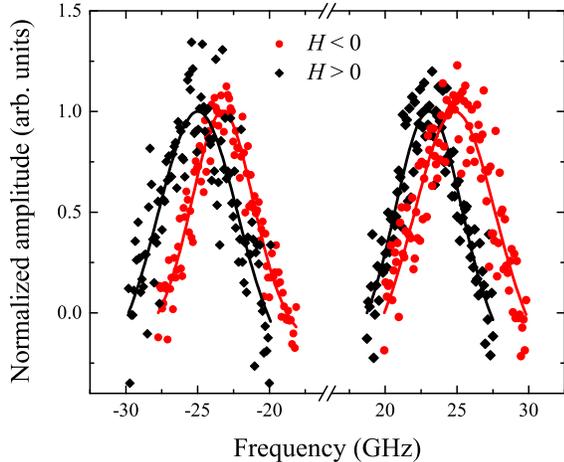


FIG. 6. BLS spectra of the Damon-Eshbach spinwave modes with a wave vector of  $k = 16.7 \mu\text{m}^{-1}$  for a sample of Pt(2 nm)/Co(1 nm)/IrMn(2.4 nm) with perpendicular magnetic anisotropy. The solid lines are fits of the data using the transmission function of the tandem multi-pass interferometer in the BLS spectrometer,  $((f - f_0)^2 - \Delta f^2)^{-6}$ , where  $f$  is the frequency,  $f_0$  is the resonance frequency, and  $\Delta f$  is the linewidth. The data are normalized using the fit.

resents the DMI contribution from the top and bottom interfaces ( $D_s = D_{\text{eff}} t_{\text{FM}}$ , where  $t_{\text{FM}}$  is the FM layer thickness). Thus,  $D_s$  should be independent of the FM layer thickness, if we consider the DMI to be a truly interfacial effect. Figure 6 shows representative BLS spectra for a sample of Pt(2 nm)/Co(1 nm)/IrMn(2.4 nm), where shifts in Stokes (negative frequencies) and anti-Stokes (positive frequencies) peaks are evident, corresponding to  $\Delta f = -0.90 \pm 0.05$  GHz. We applied in-plane fields of less than 1.3 T for the BLS measurements.

The saturation magnetization is measured by a superconducting quantum interference device (SQUID) VSM. For Pt/Co/IrMn,  $M_s = (1.36 \pm 0.05) \times 10^6$  A/m, which is similar to the value for bulk Co. For Pt/Co/FeMn,  $M_s = (2.33 \pm 0.05) \times 10^6$  A/m. The high value in this case may be due to the formation of a monolayer of Fe at the Co/FeMn interface [43], which contributes to the total moment. Thus, to account for this, we increase the effective volume of the FM layer by including a monolayer of Fe and we arrive at a value of  $M_s = (1.57 \pm 0.04) \times 10^6$  A/m.

The magnitude of the DMI of the two systems at different AFM layer thicknesses are summarized in Table I. The spin order of the AFM layers does not affect the DMI, when measured using this technique. To assess this, we measured the DMI of the IrMn system at four critical thicknesses of the IrMn layer, which correspond to the paramagnet phase (sample (a)) with no spin order, the AFM phase at the point of paramagnet-to-AFM phase transition (sample (b)) with no EB, the AFM phase at

peak coercivity (sample (c)) when the EB starts to set in, and the AFM phase with a large EB (sample (d)) brought about by a larger anisotropy energy of the AFM layer as being thicker. The magnitude of the DMI remains the same in all four cases, from which we conclude that neither the spin order of the AFM layer nor the EB play a role in the mechanism of the DMI in this system. The same behavior occurs in the FeMn system. The DMI of the system when the FeMn layer is paramagnetic (sample (e)) is the same when it is antiferromagnetic (sample (f)). It was not possible to measure the DMI for samples with a large EB: a thick FeMn layer reduces the backscattered signal, and the very thin Co layer has large linewidth because of spin-pumping and two-magnon scattering due to the presence of the AFM layer. Both systems possess left-handed chirality (counter-clockwise).

According to the three-site model of Fert and Levy [44], a DM-type interaction occurs when an impurity atom, due to the spin-orbit coupling (SOC) of its conduction electrons, mediates an exchange interaction between two magnetic atoms. The SOC constant does not depend on the spin state but rather on the atomic number. Hence, the DMI is not influenced by the spin order of the AFM layer. Our experiment is in accordance with this model.

Our measurements show that the DMI remains unchanged with and without the presence of an EB field. However, we do note that the change in DMI at the CoFeB/IrMn interface as the IrMn film thickness is increased from 1 to 8 nm is of the order of  $0.1 \text{ mJ/m}^2$  [22]. We cannot rule out a similar change in our Co/IrMn system because such a value falls within our experimental uncertainty. The relatively large error for sample (d) is again due to the presence of a thick AFM IrMn layer.

The FeMn system has a different  $D_s$  than the IrMn system. This indicates that the DMI is different at the two interfaces of Co/IrMn and Co/FeMn, as the Pt/Co interface is common to both. This could be expected due to the difference in Mn concentration for the two AFMs (Mn atoms mostly contribute to the DMI [22]). This is the case for a “clean” Co/FeMn interface. However, the formation of an Fe layer at the Co/FeMn interface could mean that we need to consider the contribution of both ferromagnetic Fe and Co to the DMI. Furthermore, due to intermixing, CoMn, which is antiferromagnetic, could also play a role in the generation of the DMI. We also point out here that although the quantity  $D_s$  is normalized with respect to the FM layer thickness, Nembach et al. [33] has shown a non-trivial relationship between the two and suggested that FM thickness could also change the interfacial DMI.

## VI. CONCLUSION

We investigated interfacial mechanisms in exchange-coupled systems of Pt/Co/IrMn and Pt/Co/FeMn exhibiting perpendicular magnetic anisotropy and perpendicular exchange bias. We control the spin order of

TABLE I. Comparison of the DMI at different phases of the AFM layers of the two investigated exchange coupled systems. The numbers in parentheses represent the nominal layer thickness in nanometers. The dominant contribution to the uncertainty in  $D_{\text{eff}}$  is the uncertainty in  $M_s$ , whereas for  $D_s$ , there is also a contribution from the uncertainty in  $t_{\text{FM}}$ , leading to a larger experimental error. For the FeMn system, the contribution of a monolayer of Fe to the volume of the FM layer and the  $M_s$  was taken into account when calculating  $D_s$  (as outlined in the text).

Sample	AFM layer spin order	Exchange bias	$D_{\text{eff}}$ (mJ/m <sup>2</sup> )	$D_s$ (pJ/m)
(a) Pt(2)/Co(1)/IrMn(1.1)	Paramagnetic	No	$-1.14 \pm 0.05$	$-1.14 \pm 0.13$
(b) Pt(2)/Co(1)/IrMn(1.7)	Antiferromagnetic	No	$-1.14 \pm 0.05$	$-1.14 \pm 0.12$
(c) Pt(2)/Co(1)/IrMn(2.4)	Antiferromagnetic	Yes	$-1.22 \pm 0.08$	$-1.22 \pm 0.15$
(d) Pt(2)/Co(1)/IrMn(5)	Antiferromagnetic	Yes	$-1.11 \pm 0.12$	$-1.11 \pm 0.16$
(e) Pt(2)/Co(0.6)/FeMn(1)	Paramagnetic	No	$-1.50 \pm 0.08$	$-1.35 \pm 0.22$
(f) Pt(2)/Co(0.6)/FeMn(2.6)	Antiferromagnetic	No	$-1.44 \pm 0.08$	$-1.30 \pm 0.21$

the antiferromagnet layers by varying the thicknesses. We study the changes in the magnetic domain morphology by magneto-optical imaging, and the interfacial Dzyaloshinskii-Moriya interaction by Brillouin light scattering spectroscopy. We demonstrate that the domain structure in these systems is influenced by the AFM Néel order. The domain texture changes from large domains with unreversed networks to isolated bubbles with smooth DWs at the onset of AFM order. The DWs become rough due to pinning as the exchange bias field develops. These changes are linked to the anisotropy energy of the AFM layer and the FM-AFM inter-layer exchange coupling. The DMI is not influenced by the AFM spin order within experimental uncertainty, in agreement with

theory.

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